

# 66A, 300V Ultrafast Dual Diode

#### **Description**

The A□F66U30DNN is an ultrafast dual diode with low forward voltage drop. This device is designed for

FWD in motor and power switching applications, It is specially suited for use in switching power supplies and industrial applications as welder.

#### **Features**

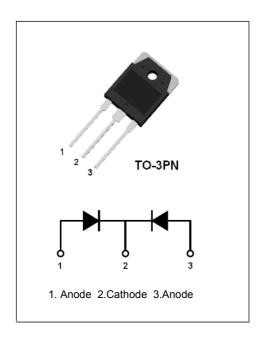
• Ultrafast Soft Recovery: T<sub>rr</sub>=55ns (max)

• Typical Forward Voltage: V<sub>F</sub>=0.99V @ I<sub>F</sub>=33A

Reverse Voltage: V<sub>RRM</sub>=300V
 Avalanche Energy Rated

#### **Applications**

- Power Switching Circuits
- Output Rectifier in Switching Power Supply & Welder
- FWD for Motor Application



#### **Absolute Maximum Ratings** per diode at $T_c$ =25 $^{\circ}$ C unless otherwise noted

Symbol	Parameter		Ratings	Unit
V <sub>RRM</sub>	Peak Repetitive Reverse Voltage		300	V
$V_{RWM}$	Working Peak Reverse Voltage		300	V
V <sub>R</sub>	DC Blocking Voltage		300	V
I <sub>F(AV)</sub>	Average Rectified Forward Current	per device at T <sub>C</sub> =120°C	66	Α
I <sub>FSM</sub>	Non-repetitive Peak Surge Current		300	Α
T <sub>J</sub>	Operating Junction Temperature Range		-65~+150	$^{\circ}$
T <sub>STG</sub>	Storage Temperature Range		-65~+150	$^{\circ}$

#### **Thermal Characteristics**

Symbol	Parameter	Ratings	Unit	
R <sub>th (J-C)</sub>	Thermal Resistance, Junction to case	0.53	°C/W	

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#### **Electrical Characteristics** per diode $@T_c$ =25 $^{\circ}$ C unless otherwise noted

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
V <sub>F</sub>	Forward Voltage Drop	I <sub>F</sub> =33A	-	0.99	1.4	V
		I <sub>F</sub> =33A, T <sub>C</sub> =125℃	-	-	1.1	V
I <sub>R</sub>	Reverse Leakage Current	V <sub>R</sub> =300V	-	-	100	uA
T <sub>rr</sub>	Reverse Recovery Time	I <sub>F</sub> =33A, di/dt=-200A/us	-	-	55	ns
E <sub>AS</sub>	Avalanche Energy	L=30mH	20	-	-	mJ

## **Typical Performance Characteristics**

Fig. 1. Typical Characteristics:  $V_F$  vs.  $I_F$ 

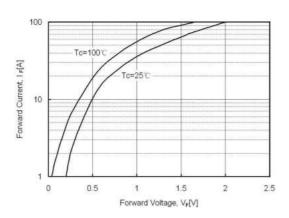


Fig. 2. Typical Characteristics:  $V_R$  vs.  $I_R$ 

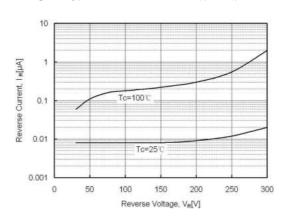


Fig. 3. Typical Reverse Recovery Time vs. di/dt

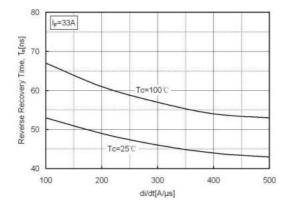
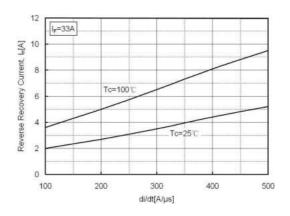


Fig. 4. Typical Reverse Recovery Current vs. di/dt

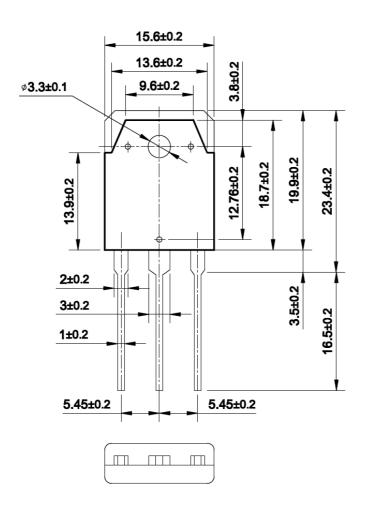


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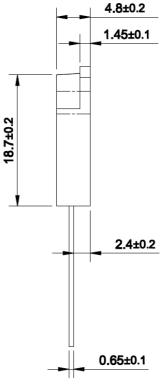


### **Package Dimensions**

TO-3PN



(Dimensions in Millimeters)
4.8±0.



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